

N-channel 600 V, 0.160 ohm, 19 A PowerFLAT™ 8x8 HV ultra low gate charge M...

Manufacturers	<a href="#">STMicroelectronics, Inc</a>
Package/Case	TO-263
Product Type	Discrete Semiconductors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for 26NM60N or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

26NM60N is a specific model number for a power MOSFET, which is a type of transistor commonly used in electronic circuits.

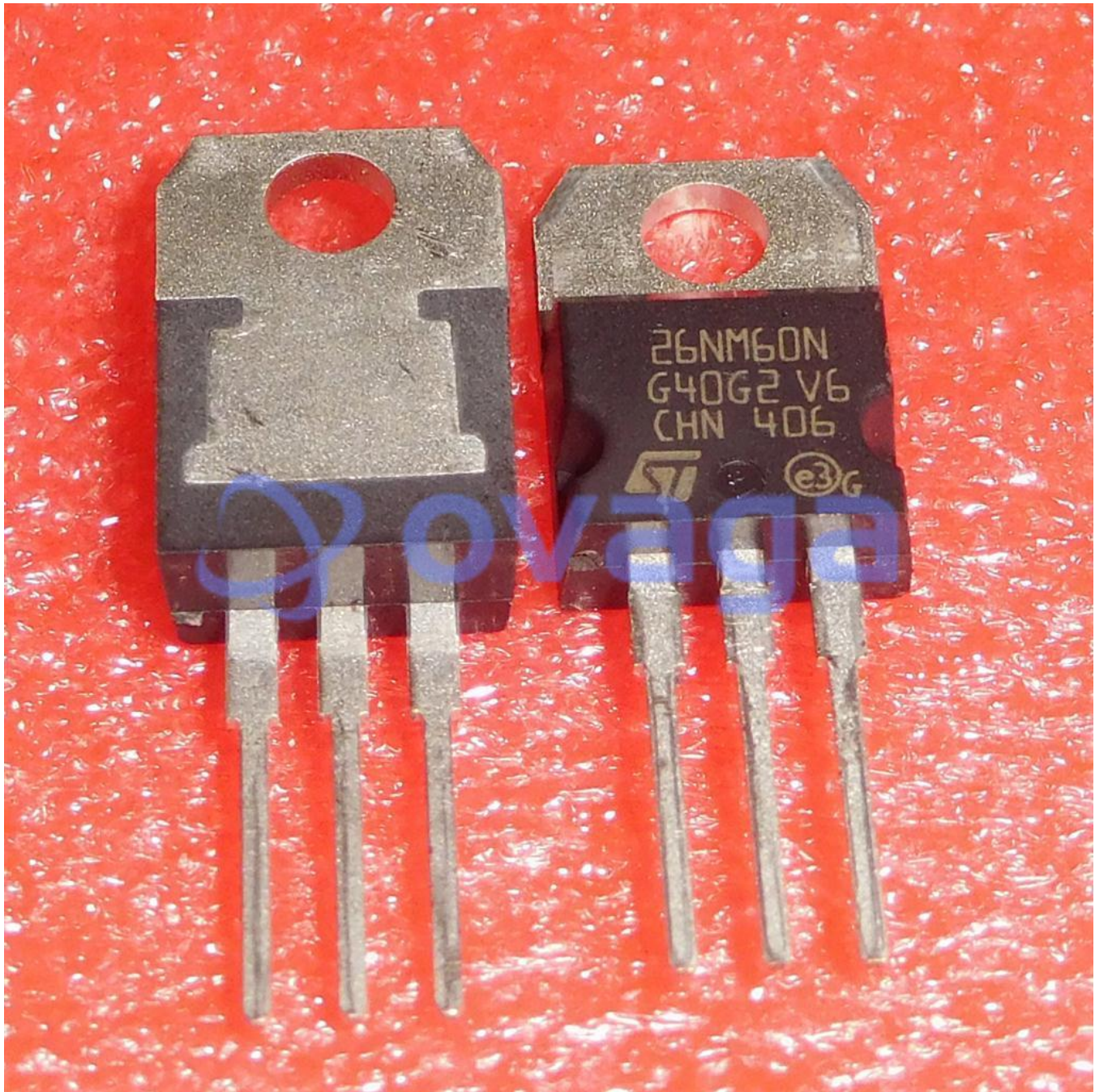
### Features

- Maximum Drain-Source Voltage (V<sub>dss</sub>) of 600V
- Continuous Drain Current (I<sub>d</sub>) of 26A
- Low Drain-Source On-Resistance (R<sub>ds(on)</sub>) of 0.16 ohm
- Fast switching speed
- High input impedance

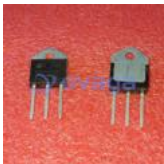
### Application

- Switching power supplies
- Motor control circuits
- Lighting control circuits
- Audio amplifiers
- Voltage regulators
- DC-DC converters



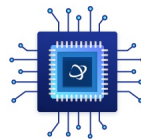


### Related Products



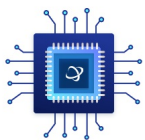
#### [BTA26-800B](#)

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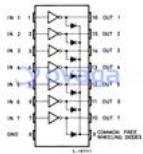
**A2C11827-BD**

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**ULQ2003D**

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**78M05**

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TO-252